

## PNP SILICON POWER TRANSISTORS

D45H2A transistor is designed for use in general purpose Power amplifier,regulator switching circuits application

### FEATURES:

- \* Collector-Emitter Voltage  
 $V_{CEO} = 30V(\text{Min})$
- \* High Current Power Transistors
- \* DC Current Gain  
 $hFE = 70 (\text{Min.}) @ I_C = 8.0A$

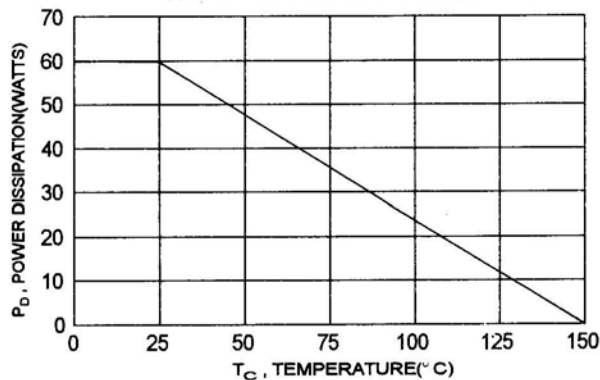
### MAXIMUM RATINGS

Characteristic	Symbol	D45H2A	Unit
Collector-Emitter Voltage	$V_{CEO}$	30	V
Collector-Base Voltage	$V_{CBO}$	30	V
Emitter-Base Voltage	$V_{EBO}$	5.0	V
Collector Current - Continuous - Peak	$I_C$ $I_{CM}$	10 20	A
Total Power Dissipation @ $T_C = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	60 0.48	W W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	$T_J, T_{STG}$	-55 to +150	$^\circ\text{C}$

### THERMAL CHARACTERISTICS

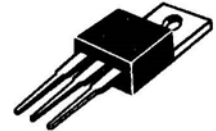
Characteristic	Symbol	Max	Unit
Thermal Resistance Junction to Case	$R_{\theta jc}$	2.08	$^\circ\text{C/W}$

FIGURE -1 POWER DERATING

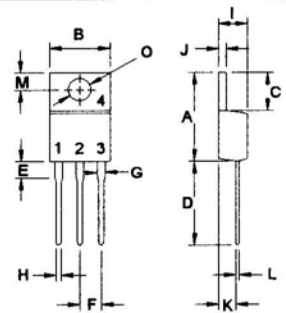


## PNP D45H2A

10 AMPERE  
POWER  
TRANSISTORS  
30 VOLTS  
60 WATTS



TO-220



PIN 1.BASE  
2.COLLECTOR  
3.EMITTER  
4.COLLECTOR(CASE)

DIM	MILLIMETERS	
	MIN	MAX
A	14.68	16.00
B	9.78	10.42
C	5.02	6.60
D	13.00	14.62
E	3.10	4.19
F	2.41	2.67
G	1.10	1.67
H	0.69	1.01
I	3.21	4.98
J	1.14	1.40
K	2.20	3.30
L	0.28	0.61
M	2.48	3.00
O	3.50	4.00

ELECTRICAL CHARACTERISTICS (  $T_C = 25^\circ\text{C}$  unless otherwise noted )

Characteristic	Symbol	Min	Max	Unit
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## OFF CHARACTERISTICS

Collector-Emitter Voltage ( $I_C = 30\text{ mA}$ , $I_B = 0$ )	$V_{CE0}$	30		V
Collector Cutoff Current ( $V_{CB} = 30\text{ V}$ , $I_E = 0$ )	$I_{CBO}$		10	$\mu\text{A}$
Emitter Cutoff Current ( $V_{EB} = 5.0\text{ V}$ , $I_C = 0$ )	$I_{EBO}$		100	$\mu\text{A}$

## ON CHARACTERISTICS (1)

DC Current Gain ( $I_C = 8.0\text{ A}$ , $V_{CE} = 1.0\text{ V}$ )	$h_{FE}$	70		
Collector-Emitter Saturation Voltage ( $I_C = 8.0\text{ A}$ , $I_B = 400\text{ mA}$ )	$V_{CE(sat)}$		0.6	V
Base-Emitter Saturation Voltage ( $I_C = 8.0\text{ A}$ , $I_B = 400\text{ mA}$ )	$V_{BE(sat)}$		1.5	V

(1) Pulse Test: Pulse Width  $\approx 300\mu\text{ s}$ , Duty Cycle  $\leq 2.0\%$ :

FIG-2 DC CURRENT GAIN

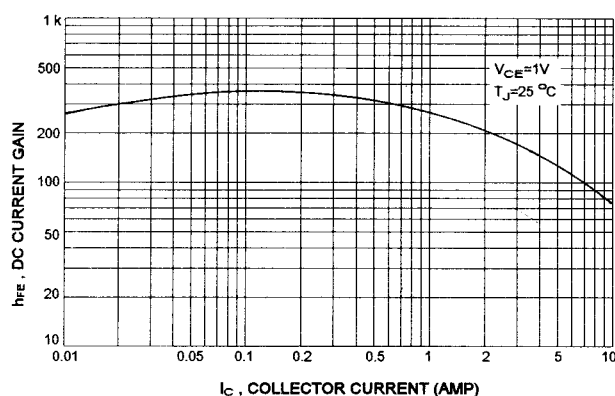


FIG-3 COLLECTOR SATURATION REGION

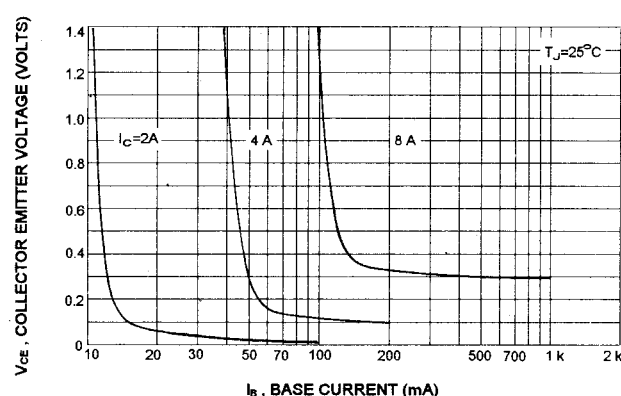
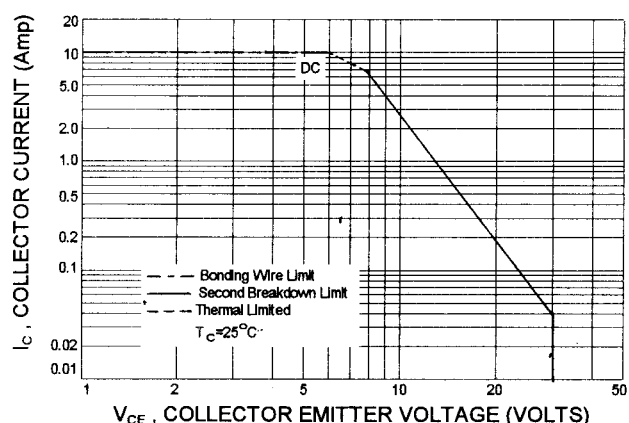


FIG-4 SAFE OPERATING AREA



There are two limitation on the power handling ability of a transistor: average junction temperature and second breakdown safe operating area curves indicate  $I_C$ - $V_{CE}$  limits of the transistor that must be observed for reliable operation i.e., the transistor must not be subjected to greater dissipation than curves indicate.

The data of FIG-4 is base on  $T_{J(PK)} = 150^\circ\text{C}$ ;  $T_C$  is variable depending on power level. second breakdown pulse limits are valid for duty cycles to 10% provided  $T_{J(PK)} < 150^\circ\text{C}$ . At high case temperatures, thermal limitation will reduce the power that can be handled to Values less than the limitations imposed by second breakdown.

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